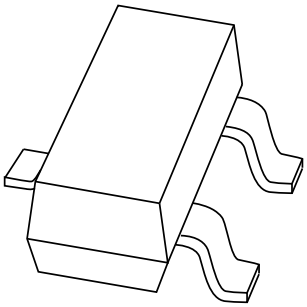
DATA SHEET



BAP65-05
Silicon PIN diode

Product specification

2001 May 07

Silicon PIN diode BAP65-05

FEATURES

- Two elements in common cathode configuration
- High voltage, current controlled
- RF resistor for RF switches
- Low diode capacitance
- Low diode forward resistance (low loss).

APPLICATIONS

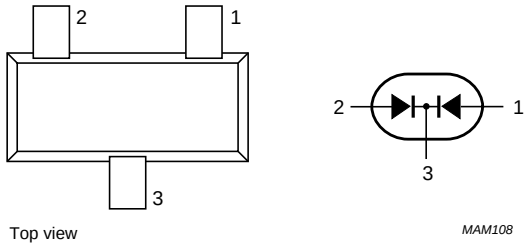
- RF attenuators and switches
- Bandswitch for TV tuners
- Series diode for mobile communication transmit-receive switch.

DESCRIPTION

Tow planar PIN diodes in a SOT23 small SMD plastic package.

PINNING

PIN	DESCRIPTION
1	anode (a_1)
2	anode (a_2)
3	common cathode



Marking code: 7Kp.

Fig.1 Simplified outline (SOT23) and symbol.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V_R	continuous reverse voltage		–	30	V
I_F	continuous forward current		–	100	mA
P_{tot}	total power dissipation	$T_s \leq 90$ °C	–	250	mW
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–65	+150	°C

ELECTRICAL CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode					
V_F	forward voltage	I_F = 50 mA	0.9	1.1	V
I_R	reverse leakage current	V_R = 20 V	–	20	nA
C_d	diode capacitance	V_R = 0 V; f = 1 MHz	0.7	–	pF
		V_R = 1 V; f = 1 MHz	0.575	0.9	pF
		V_R = 3 V; f = 1 MHz	0.525	0.8	pF
		V_R = 20 V; f = 1 MHz	0.425	–	pF
r_D	diode forward resistance	I_F = 1 mA; f = 100 MHz	1	–	Ω
		I_F = 5 mA; f = 100 MHz; note 1	0.65	0.95	Ω
		I_F = 10 mA; f = 100 MHz; note 1	0.56	0.9	Ω
		I_F = 100 mA; f = 100 MHz	0.35	–	Ω
$\|s_{21}\|^2$	isolation	V_R = 0; f = 900 MHz	9.4	–	dB
		V_R = 0; f = 1800 MHz	4.8	–	dB
		V_R = 0; f = 2450 MHz	3.1	–	dB
$\|s_{21}\|^2$	insertion loss	I_F = 1 mA; f = 900 MHz	0.1	–	dB
		I_F = 1 mA; f = 1800 MHz	0.18	–	dB
		I_F = 1 mA; f = 2450 MHz	0.28	–	dB
$\|s_{21}\|^2$	insertion loss	I_F = 5 mA; f = 900 MHz	0.08	–	dB
		I_F = 5 mA; f = 1800 MHz	0.16	–	dB
		I_F = 5 mA; f = 2450 MHz	0.26	–	dB
$\|s_{21}\|^2$	insertion loss	I_F = 10 mA; f = 900 MHz	0.07	–	dB
		I_F = 10 mA; f = 1800 MHz	0.15	–	dB
		I_F = 10 mA; f = 2450 MHz	0.25	–	dB
$\|s_{21}\|^2$	insertion loss	I_F = 100 mA; f = 900 MHz	0.06	–	dB
		I_F = 100 mA; f = 1800 MHz	0.14	–	dB
		I_F = 100 mA; f = 2450 MHz	0.24	–	dB
τ_L	charge carrier life time	when switched from I_F = 10 mA to I_R = 6 mA; R_L = 100 Ω; measured at I_R = 3 mA	0.17	–	μs
L_S	series inductance	I_F = 100 mA; f = 100 MHz	1.4	–	nH

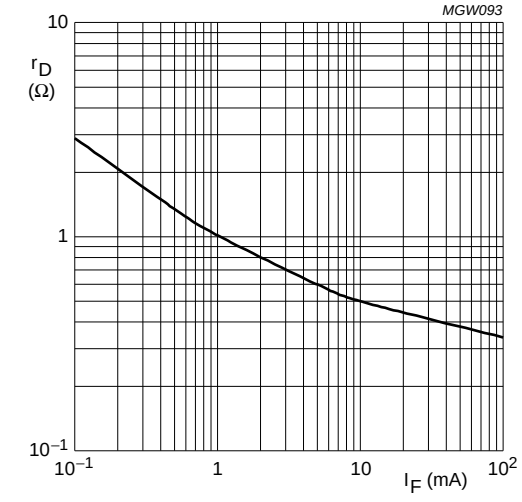
Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

THERMAL CHARACTERISTICS

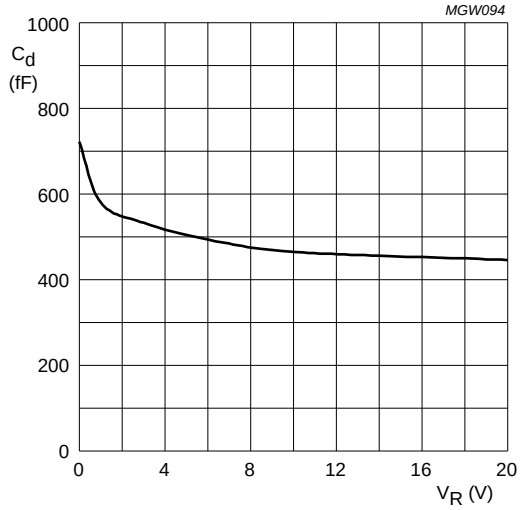
SYMBOL	PARAMETER	VALUE	UNIT
$R_{th\ j\text{-}s}$	thermal resistance from junction to soldering point	220	K/W

GRAPHICAL DATA



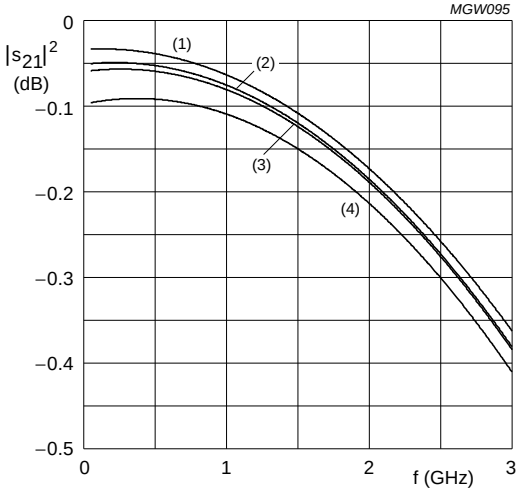
f = 100 MHz; T_j = 25 °C.

Fig.2 Forward resistance as a function of forward current; typical values.



f = 1 MHz; T_j = 25 °C.

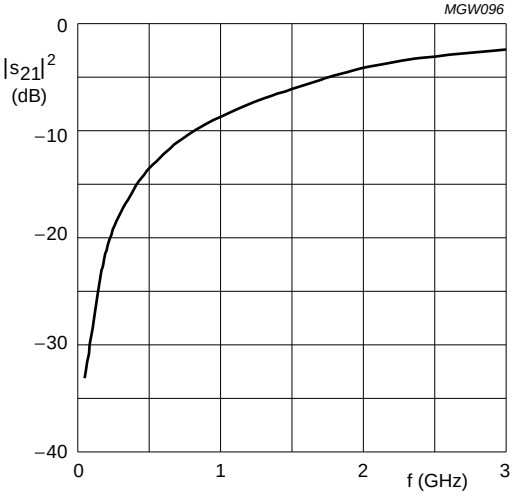
Fig.3 Diode capacitance as a function of reverse voltage; typical values.



(1) I_F = 100 mA.
(2) I_F = 10 mA.
(3) I_F = 5 mA.
(4) I_F = 1 mA.

Diode inserted in series with a 50 Ω stripline circuit and biased via the analyzer Tee network.
T_{amb} = 25 °C.

Fig.4 Insertion loss ($|s_{21}|^2$) of the diode in on-state as a function of frequency; typical values.

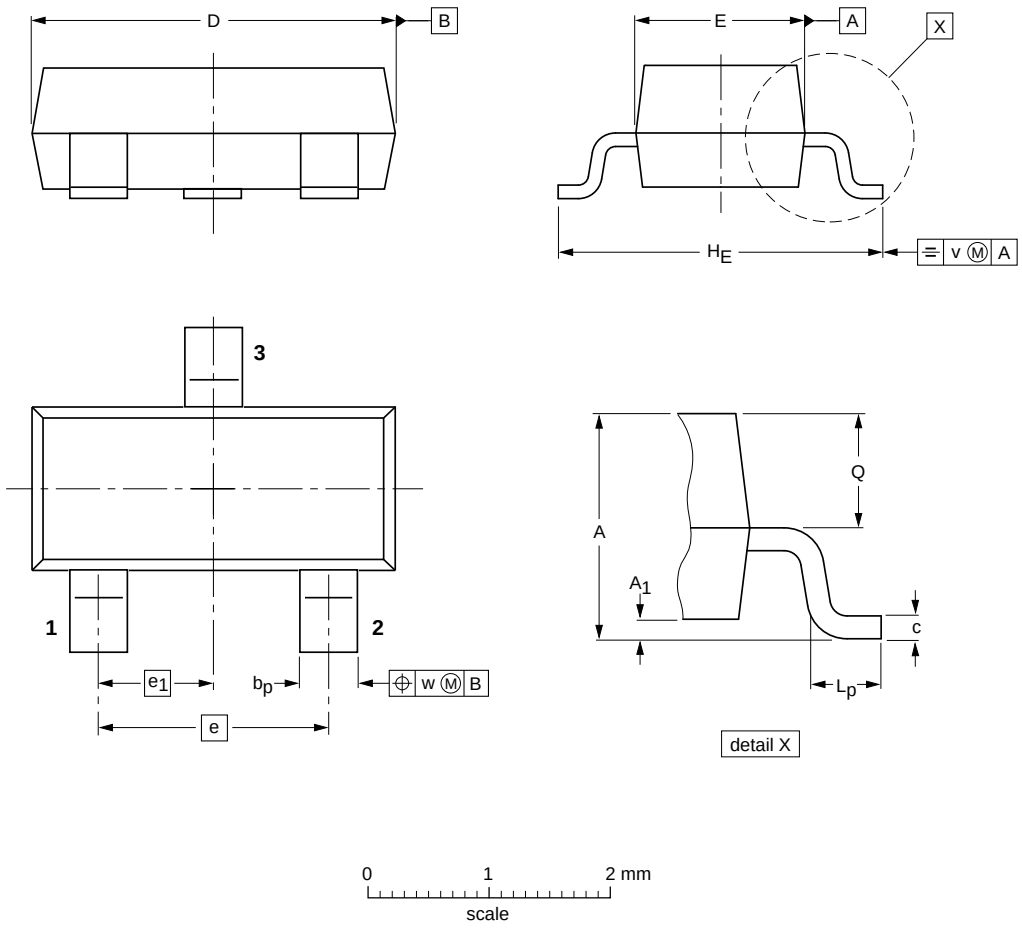


Diode zero biased and inserted in series with a 50 Ω stripline circuit.
T_{amb} = 25 °C.

Fig.5 Isolation ($|s_{21}|^2$) of the diode in off-state as a function of frequency; typical values.

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads **SOT23**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max.	b_p	c	D	E	e	e_1	H_E	L_p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT23		TO-236AB				~~04-11-04~~ 06-03-16

DATA SHEET STATUS

DOCUMENT STATUS[1]	PRODUCT STATUS[2]	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

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